**Features**

- Low forward voltage drop
- High reverse voltage
- Hermetic metal cases with ceramic insulators

Typical Applications

- All purpose high power rectifier diodes
- High power resistance welding equipment
- Non-controllable and half-controllable rectifiers
- Controlled rectifiers

Part No. Y70ZPC-ZT60cT

I_{F(AV)}	4520A	
V_{RRM}	1200V	1400V
	1600V	1800V
	2000V	

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T _J (°C)	VALUE			UNIT
				Min	Type	Max	
I _{F(AV)}	Mean forward current	180 half sine wave 50Hz Double side cooled, T _C =85 °C	175			4520	A
V _{RRM}	Repetitive peak reverse voltage	tp=10ms	175	1100		2000	V
I _{RRM}	Repetitive peak current	at V _{RRM}	175			160	mA
I _{FSM}	Surge forward current	10ms half sine wave	175			44	kA
I ² t	I ² t for fusing coordination	V _R =0.6V _{RRM}				9680	A ² s*10 ³
V _{FO}	Threshold voltage		175			0.85	V
r _F	Forward slope resistance					0.073	mΩ
V _{FM}	Peak forward voltage	I _{FM} =4000A, F=35kN	25			2.0	V
Q _{rr}	Recovery charge	I _{FM} =2000A, tp=4000μs, di/dt=-20A/μs, V _R =100V	175		5000		μC
R _{th(j-c)}	Thermal resistance Junction to case	At 180° sine double side cooled Clamping force 35kN				0.012	C/W
R _{th(c-h)}	Thermal resistance case to heat sink					0.003	
F _m	Mounting force			30		40	kN
T _{vj}	Junction temperature			-40		175	°C
T _{stg}	Stored temperature			-40		175	°C
W _t	Weight				880		g
Outline	ZT60cT						

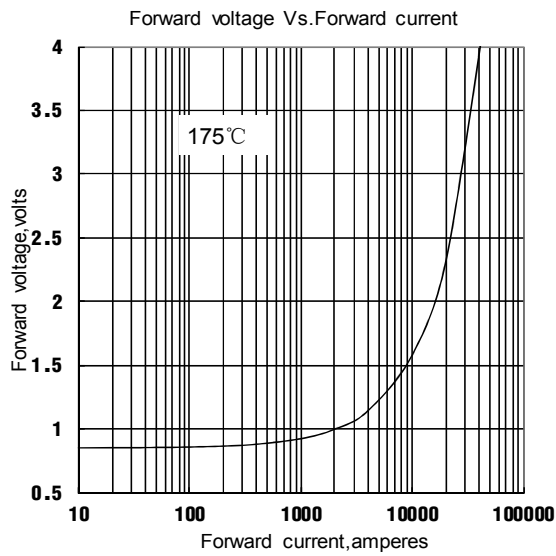


Fig.1

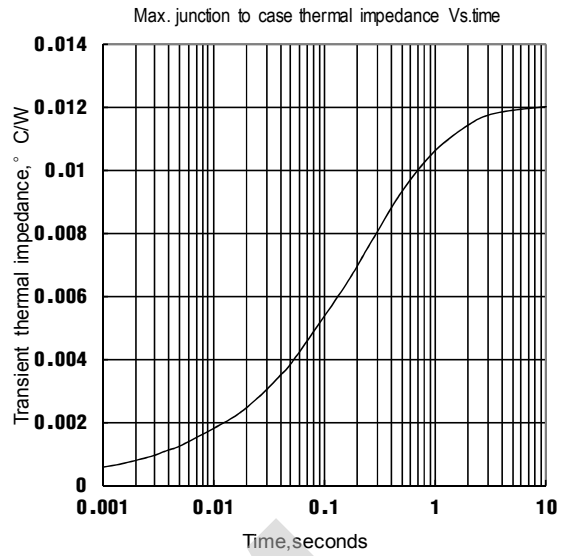


Fig.2

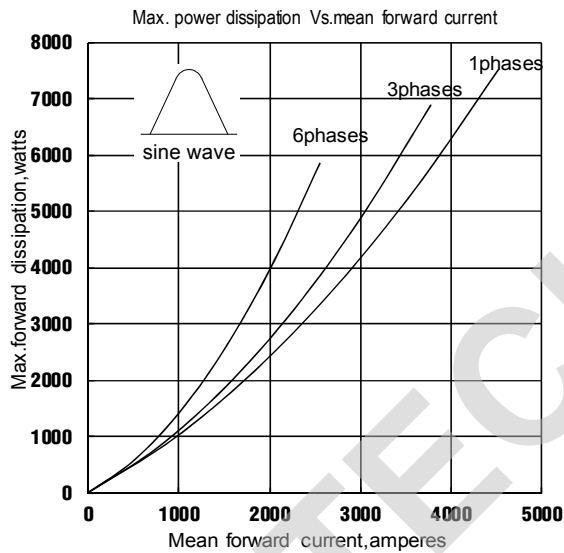


Fig.3

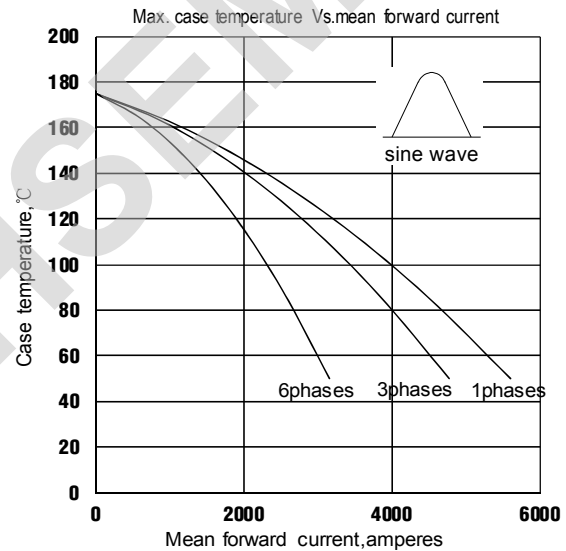


Fig.4

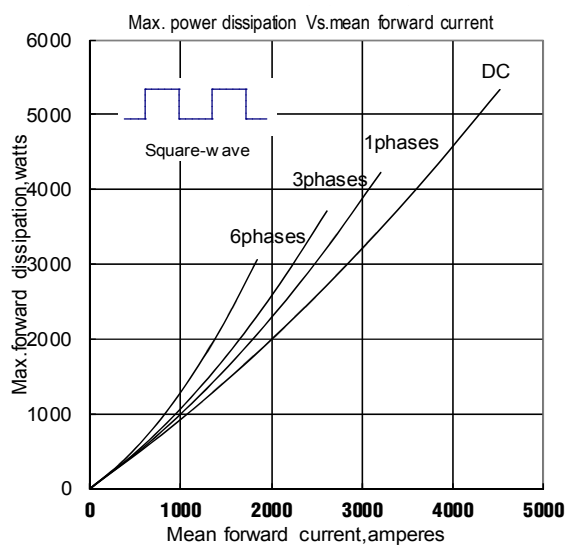


Fig.5

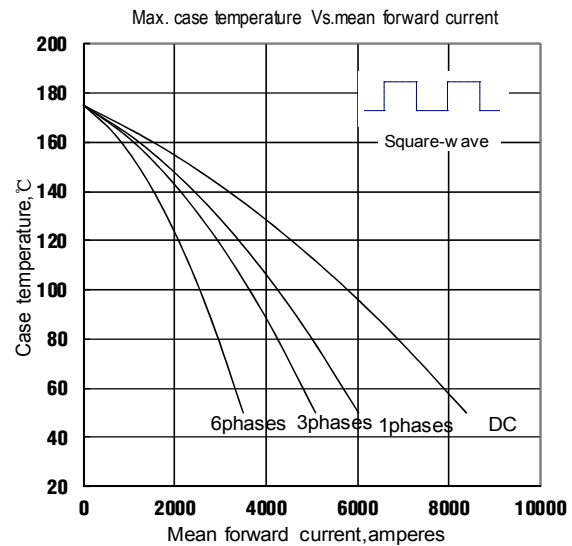


Fig.6

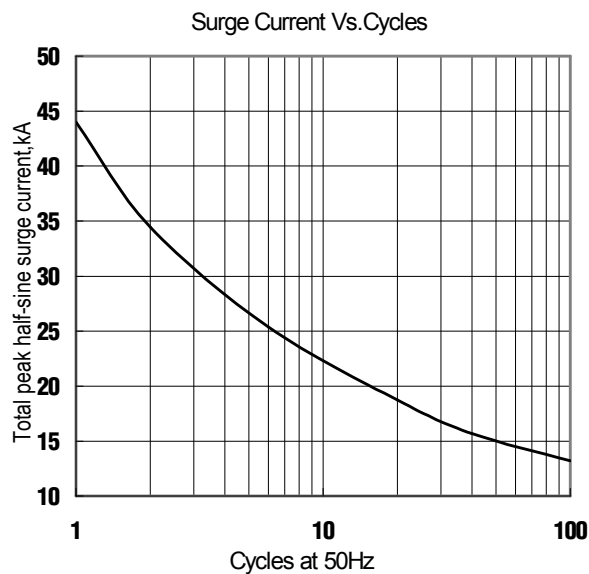


Fig.7

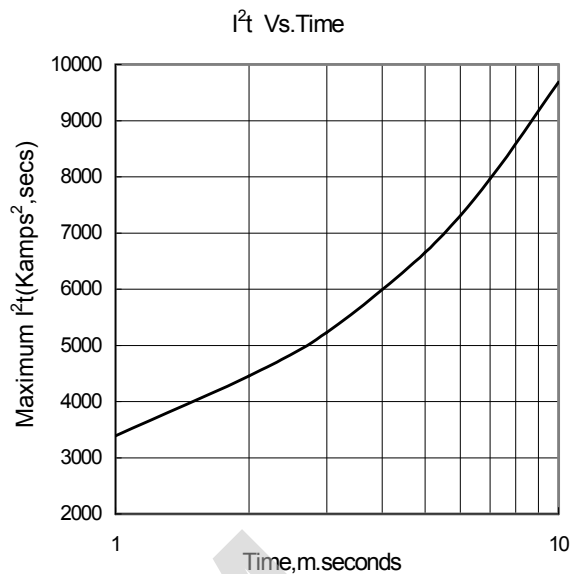
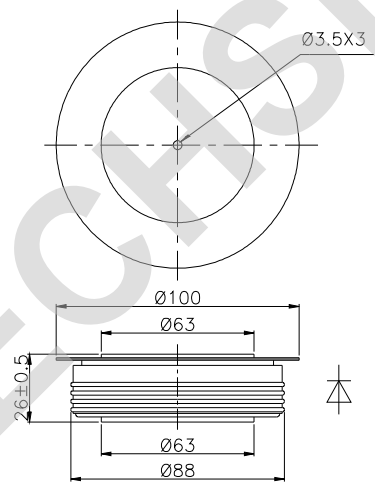


Fig.8

Outline:



TECHSEM reserves the right to change specifications without notice.